

600V N-Channel MOSFET

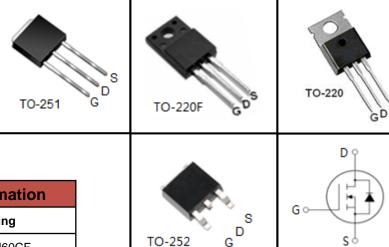
FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

Device Marking and Package Information					
Device	Package	Marking			
CS7N60CF	TO-220F	CS7N60CF			
CS7N60CP	TO-220	CS7N60CP			
CS7N60CU	TO-251	CS7N60CU			
CS7N60CD	TO-252	CS7N60CD			



Absolute Maximum Ratings $T_c = 25^{\circ}C$, unless otherwise noted							
Parameter	Symbol	Value					
	Symbol	TO-220	TO-220F	TO-251	TO-252	Unit	
Drain-Source Voltage ($V_{GS} = 0V$)	V _{DSS}	600		V			
Continuous Drain Current	I _D	7			А		
Pulsed Drain Current (note1)	I _{DM}	28			А		
Gate-Source Voltage	V _{GSS}	±30			V		
Single Pulse Avalanche Energy (note2)	E _{AS}	180			mJ		
Avalanche Current (note1)	I _{AS}	6			А		
Repetitive Avalanche Energy (note1)	E _{AR}	108			mJ		
Power Dissipation ($T_c = 25^{\circ}C$)	P _D	63 83		W			
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150				°C	

Thermal Resistance							
Deservator	Symbol		L In St				
Parameter		TO-220F	TO-251	TO-252	TO-220	Unit	
Thermal Resistance, Junction-to-Case	R _{thJC}	2.3	1.5		K/W		
Thermal Resistance, Junction-to-Ambient	R _{thJA}	62.5	60				



CS7N60CF,CS7N60CP,CS7N60CU,CS7N60CD

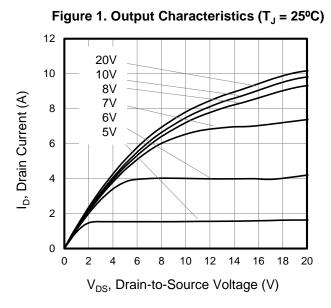
Devementer			Value			
Parameter Symbol		Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_{D} = 250 \mu A$	600			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 600V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA
Gate-Source Leakage	I _{GSS}	V_{GS} = $\pm 30V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	3.0		4.0	V
Drain-Source On-Resistance (Note3)	$R_{DS(on)}$	V _{GS} = 10V, I _D = 3.5A		1	1.2	Ω
Dynamic						
Input Capacitance	C _{iss}	$\lambda = 0 \lambda$		891		pF
Output Capacitance	C _{oss}	$V_{GS} = 0V,$ $V_{DS} = 25V,$		97		
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		14		
Total Gate Charge	Q _g			30		nC
Gate-Source Charge	Q _{gs}	$V_{DD} = 480V, I_D = 7.0A, V_{GS} = 10V$		5		
Gate-Drain Charge	Q _{gd}			14		
Turn-on Delay Time	t _{d(on)}			38		
Turn-on Rise Time	t _r	V _{DD} = 300V, I _D =7.0A,		25		
Turn-off Delay Time	t _{d(off)}	$V_{\text{DD}} = 300\text{V}, \text{ I}_{\text{D}} = 7.0\text{A},$ $\text{R}_{\text{G}} = 25 \ \Omega$		154		ns
Turn-off Fall Time	t _f			40		
Drain-Source Body Diode Character	istics					
Continuous Body Diode Current	۱ _s	T 05.00			7.0	A
Pulsed Diode Forward Current	I _{SM}	T _C = 25 °C			28	
Body Diode Voltage	V _{SD}	T _J = 25°C, I _{SD} = 3.5A, V _{GS} = 0V			1.4	V
Reverse Recovery Time	t _{rr}	V _{GS} = 0V,I _S = 7.0A,		300		ns
Reverse Recovery Charge	Q _{rr}	di _F /dt =100A /µs		1.59		μC

Notes

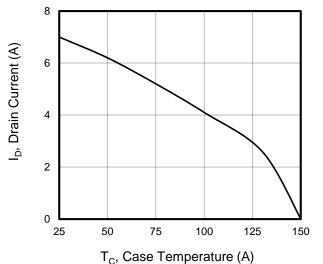
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L = 10.0mH, V_{DD} = 50V, R_G = 25 \Omega, Starting T_J = 25 °C
- 3. Pulse Test: Pulse width \leq 300µs, Duty Cycle \leq 1%



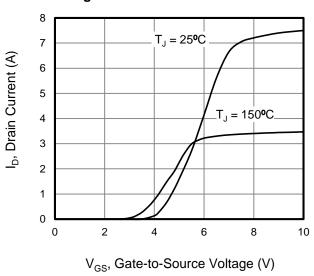
Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted











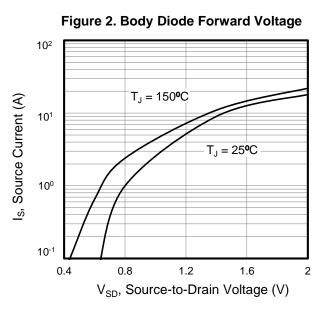


Figure 4. BV_{DSS} Variation vs. Temperature

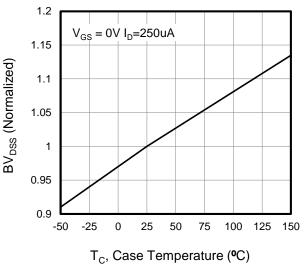
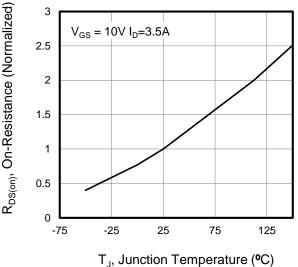
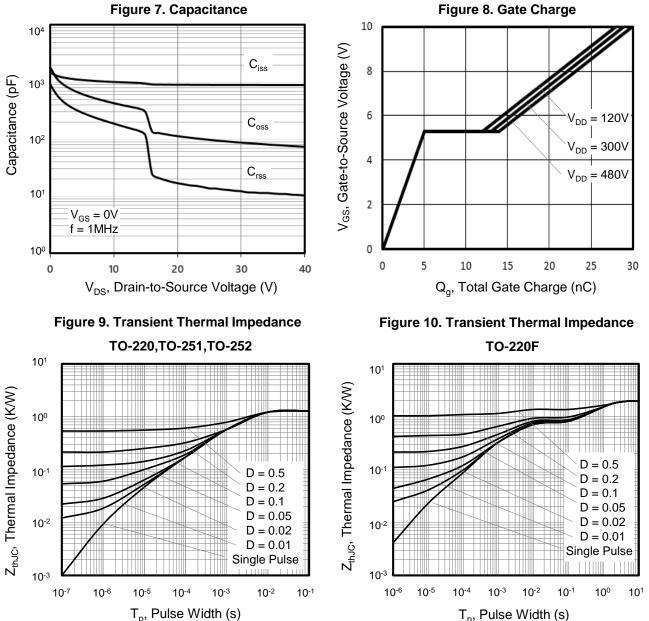


Figure 6. On-Resistance vs. Temperature





Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted



T_p, Pulse Width (s)



CS7N60CF,CS7N60CP,CS7N60CU,CS7N60CD



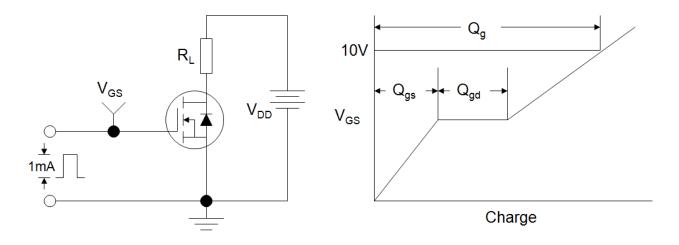


Figure B: Resistive Switching Test Circuit and Waveform

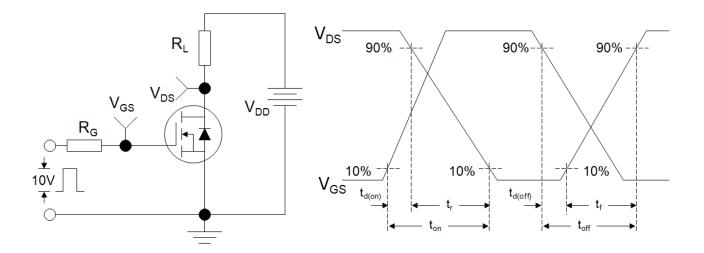
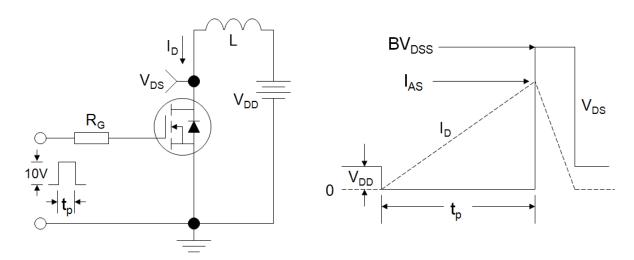


Figure C: Unclamped Inductive Switching Test Circuit and Waveform

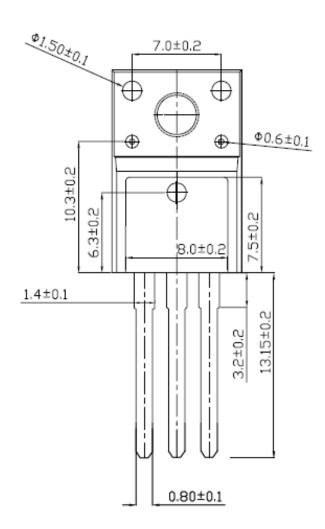


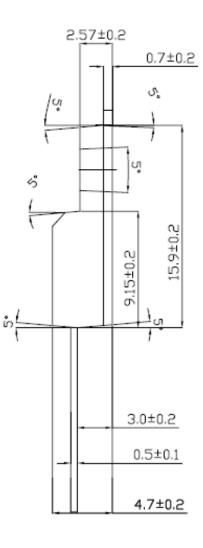
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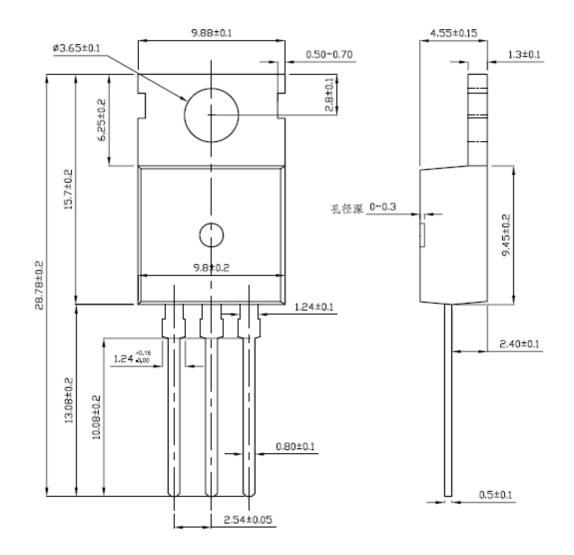
TO-220F







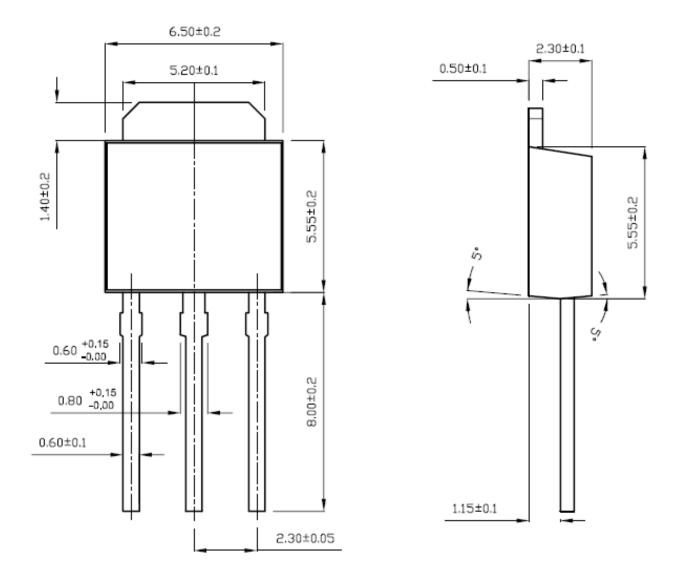
TO-220





CS7N65CU,CS7N65CD,CS7N65CF,CS7N65CP

TO-251

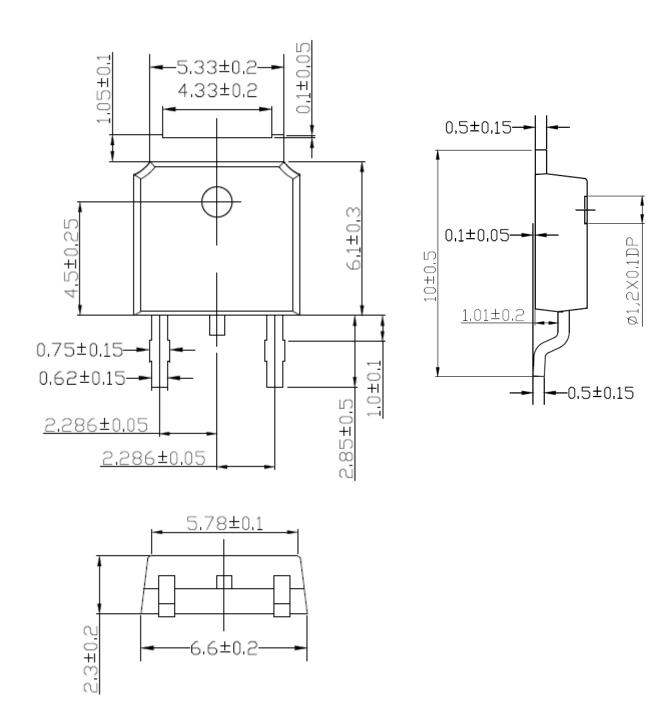


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